



**BSS138** 

#### N-CHANNEL ENHANCEMENT MODE MOSFET

### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub>	I <sub>D</sub> T <sub>A</sub> = +25°C
50V	3.5Ω @ V <sub>GS</sub> = 10V	200mA

### **Description and Applications**

This MOSFET has been designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

System/Load Switch

### **Features and Benefits**

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotive-products/.

 This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

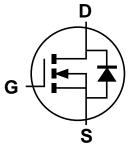
https://www.diodes.com/quality/product-definitions/

#### **Mechanical Data**

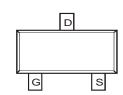
- Case: SOT23
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Alloy 42 Leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Weight: 0.008 grams (Approximate)







**Equivalent Circuit** 



Top View

### Ordering Information (Note 4)

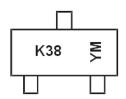
Part Number	Case	Packaging
BSS138-7-F	SOT23	3000/Tape & Reel
BSS138-13-F	SOT23	10000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/



## **Marking Information**



K38 = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: H = 2020) M or  $\overline{M}$  = Month (ex: 9 = September)

Date Code Key

Year	2003		2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	Р		Н	I	J	K	L	М	N	0	Р	R
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec

# **Maximum Ratings** (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	$V_{DSS}$	50	V
Drain-Gate Voltage R <sub>GS</sub> ≤ 20kΩ	Vdgr	50	V
Gate-Source Voltage Continuous	\/	±20	V
Gate-Source Voltage Non Repetitive, Pulse Width<50µs	Vgss	±40	V
Drain Current Continuous	lD	200	mA
Pulsed Drain Current (10µs Pulse Duty Cycle = 1%)	I <sub>DM</sub>	1	А

# Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

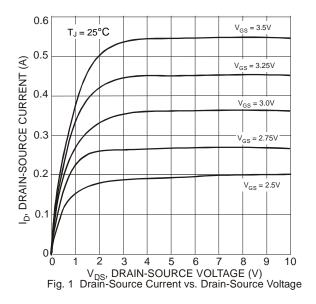
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	300	mW
Thermal Resistance, Junction to Ambient (Note 5)	$R_{ heta JA}$	417	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	50	75		V	$V_{GS} = 0V, I_{D} = 250 \mu A$
Zero Gate Voltage Drain Current	I <sub>DSS</sub>		_	0.5	μΑ	V <sub>DS</sub> = 50V, V <sub>GS</sub> = 0V
Gate-Body Leakage	Igss	_		±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 6)						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	0.5	1.2	1.5	>	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$
Static Drain-Source On-Resistance	RDS(ON)	_	1.4	3.5	Ω	$V_{GS} = 10V, I_{D} = 0.22A$
Forward Transconductance	<b>g</b> FS	100	_	_	mS	$V_{DS} = 25V$ , $I_{D} = 0.2A$ , $f = 1.0kHz$
DYNAMIC CHARACTERISTICS (Note 7)						
Input Capacitance	Ciss	_		50	рF	
Output Capacitance	Coss	_		25	pF	$V_{DS} = 10V, V_{GS} = 0V, f = 1.0MHz$
Reverse Transfer Capacitance	Crss	_		8.0	pF	
SWITCHING CHARACTERISTICS (Note 7)						
Turn-On Delay Time	tD(ON)	_		20	ns	$V_{DD} = 30V$ , $I_D = 0.2A$ , $R_{GEN} = 50\Omega$
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_		20	ns	VDD = 30V, ID = 0.2A, RGEN = 3002

 $5. \ Device mounted on FR-4\ PCB\ 1.0\ x\ 0.75\ x\ 0.062\ inch\ pad\ layout\ as\ shown\ on\ Diodes\ Incorporated's\ suggested\ pad\ layout,\ which\ can\ be\ found\ on\ our\ properties of the properties of the$ Notes: website at http://www.diodes.com/package-outlines.html.
6. Short duration pulse test used to minimize self-heating effect.
7. Guarantee by design. Not subject to production testing.





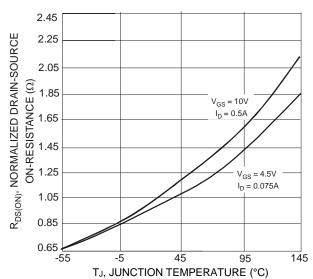


Fig. 3 Drain-Source On-Resistance vs. Junction Temperature

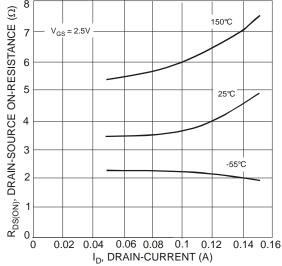
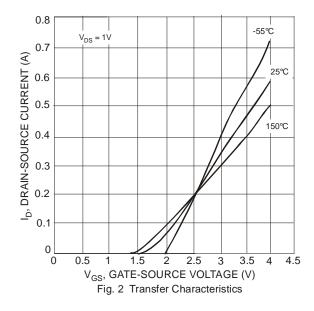
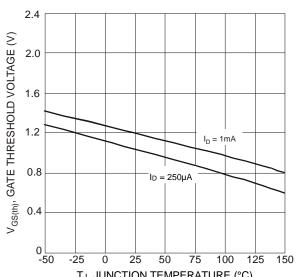


Fig. 5 Drain-Source On-Resistance vs. Drain-Current





TJ, JUNCTION TEMPERATURE (°C)
Fig. 4 Gate Threshold Variation vs. Junction Temperature

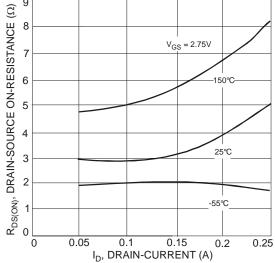


Fig. 6 Drain-Source On-Resistance vs. Drain-Current



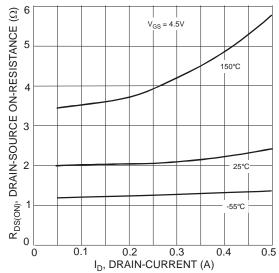
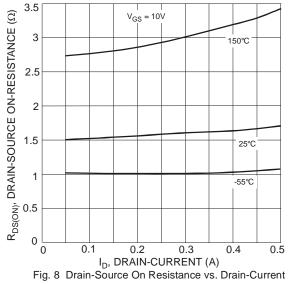
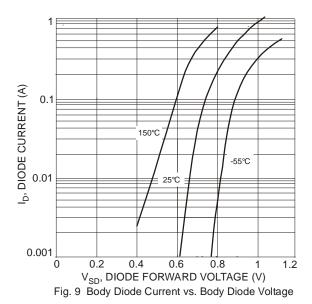
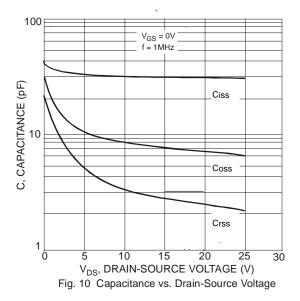


Fig. 7 Drain-Source On-Resistance vs. Drain-Current





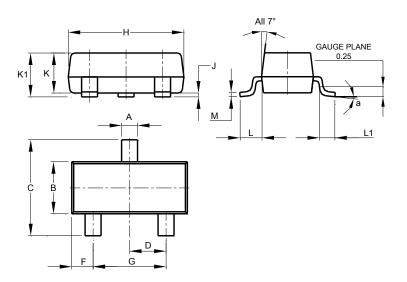




## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23

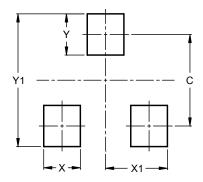


SOT23						
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
В	1.20	1.40	1.30			
С	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
Η	2.80	3.00	2.90			
7	0.013	0.10	0.05			
K	0.890	1.00	0.975			
K1	0.903	1.10	1.025			
L	0.45	0.61	0.55			
L1	0.25	0.55	0.40			
М	0.085	0.150	0.110			
а	0°	8°				
All Dimensions in mm						

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
V1	2.0



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